

10mm BAYONET BASED LED LAMP

BLB102SYC-12V-P

SUPER BRIGHT YELLOW

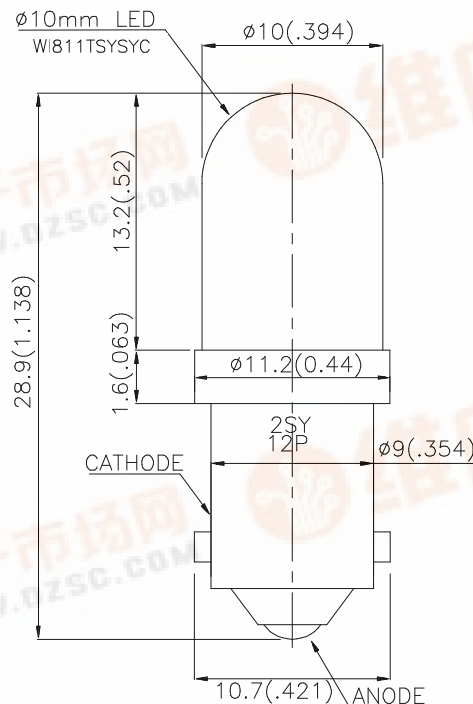
Features

- BUILT-IN CURRENT LIMITING RESISTOR FOR DIRECT APPLICATION OF DIFFERENT ACROSS CURRENT.
- LONG LIFE.
- LOW CURRENT, POWER SAVINGS.
- LOW MAINTENANCE.
- DIFFERENT COLOR AVAILABLE.
- SOLID STATE, HIGH VIBRATION RESISTANT.
- 12V INTERNAL RESISTOR

Description

The Super Bright Yellow source color devices are made with DH InGaAlP on GaAssubstrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 (0.01") unless otherwise noted.
3. Specifications are subjected to change without notice.





Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) V=12V		Viewing Angle
			Min.	Typ.	θ1/2
BLB102SYC-12V-P	SUPER BRIGHT YELLOW (InGaAlP)	WATER CLEAR	480	1200	40°

Note:

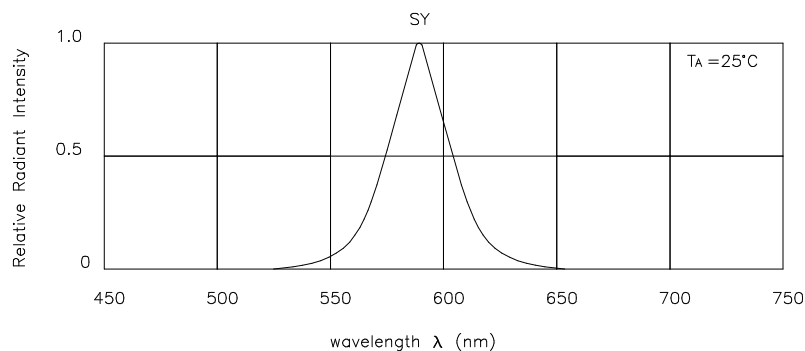
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	Super Bright Yellow	590	-	nm	V _F =12V
λ _D	Dominate Wavelength	Super Bright Yellow	588	-	nm	V _F =12V
Δλ _{1/2}	Spectral Line Half-width	Super Bright Yellow	28	-	nm	V _F =12V
I _F	Forward Current	Super Bright Yellow	19	25	mA	V _F =12V
C	Capacitance	Super Bright Yellow	25	-	pF	V _F =0V;f=1MHz
I _R	Reverse Current	Super Bright Yellow	-	10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Super Bright Yellow	Units
Power Dissipation	300	mW
Forward Voltage	14	V
Reverse Voltage	5	V
Operating Temperature	-40°C To +70°C	
Storage Temperature	-40°C To +85°C	



RELATIVE INTENSITY Vs. WAVELENGTH

Super Bright Yellow

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